

GaAs PHEMT MMIC LNA w/ FAILSAFE BYPASS MODE, 1700 - 2200 MHz



Typical Applications

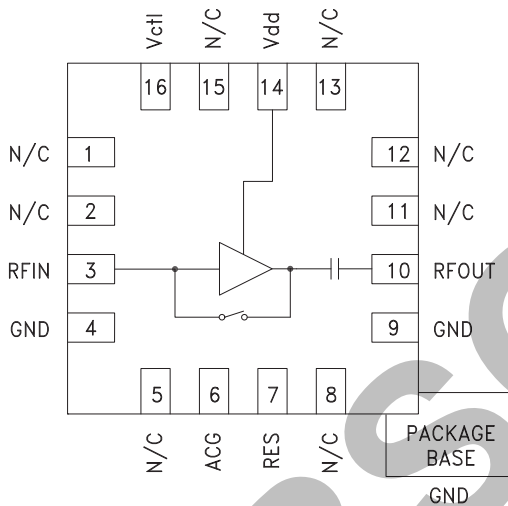
The HMC669LP3(E) is ideal for:

- Cellular/3G and LTE/WiMAX/4G
- BTS & Infrastructure
- Repeaters and Femtocells
- Tower Mounted Amplifiers
- Test & Measurement Equipment

Features

- Noise Figure: 1.4 dB
- Output IP3: +29 dBm
- Gain: 17 dB
- FailSAFE Operation:
 - Bypass is enabled when LNA is unpowered
- Single Supply: +3V or +5V
- 16 Lead 3x3mm QFN Package: 9 mm²

Functional Diagram



General Description

The HMC669LP3(E) is a versatile, high dynamic range GaAs MMIC Low Noise Amplifier that integrates a low loss LNA bypass mode on the IC. The amplifier is ideal for receivers and LNA modules operating between 1.7 and 2.2 GHz and provides 1.4 dB noise figure, 17 dB of gain and +29 dBm IP3 from a single supply of +5V @ 86mA. Input and output return losses are excellent and no external matching components are required. A single control line is used to switch between LNA mode and a low loss bypass mode. FailSAFE topology also enables the LNA bidirectional bypass path when no DC power is available.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $R_{bias} = 15\ \Omega$

Parameter	LNA Mode						Bypass Mode			FailSAFE Mode			Units
	Vdd = +3V			Vdd = +5V			Min.	Typ.	Max.	Min.	Typ.	Max.	
	Min.	Typ.	Max.	Min.	Typ.	Max.							
Frequency Range	1.7 - 2.2			1.7 - 2.2			1.7 - 2.2			1.7 - 2.2			GHz
Gain	12	15		14	17		-3	-2.1		-3	-2.1		dB
Gain Variation Over Temperature	0.015			0.014			0.0008			0.0008			dB / °C
Noise Figure	1.4			1.65			1.4			1.65			dB
Input Return Loss	10			11			12			12			dB
Output Return Loss	13			13			12			12			dB
Reverse Isolation	28			30			-			-			dB
Power for 1dB Compression (P1dB) ^[1]	11.5			12			21			24			dBm
Third Order Intercept (IP3) ^[2]	25			29			25			25			dBm
Supply Current (Idd)	49			59			86			105			mA
Switching Speed													
LNA Mode to Bypass Mode							80						ns
Bypass Mode to LNA Mode	100			100									ns

[1] P1dB for LNA Mode is referenced to RFOUT while P1dB for Bypass and FailSAFE Modes are referenced to RFIN.

[2] IP3 for LNA Mode is referenced to RFOUT while IP3 for Bypass and FailSAFE Modes are referenced to RFIN.

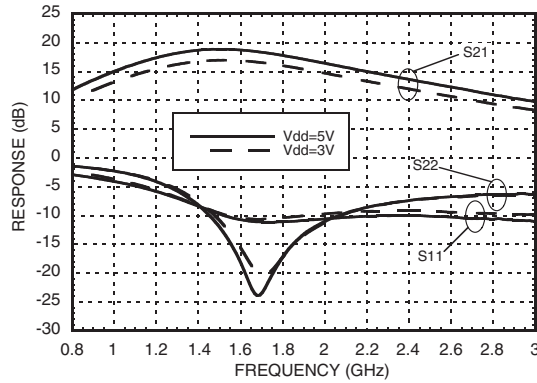


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

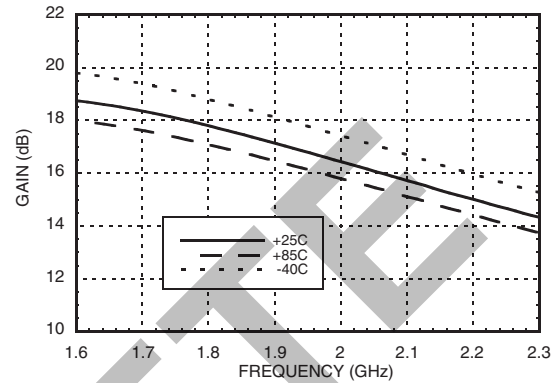
7

AMPLIFIERS - LOW NOISE - SMT

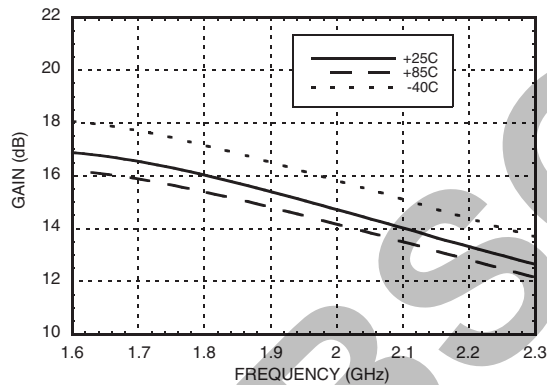
LNA - Broadband Gain & Return Loss



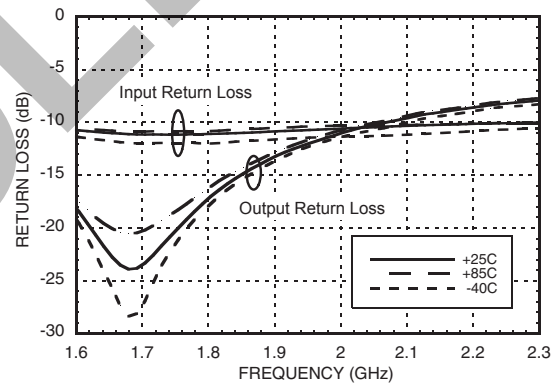
LNA - Gain vs. Temperature [1]



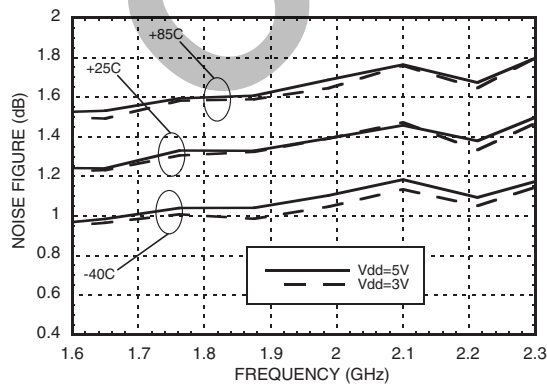
LNA - Gain vs. Temperature [2]



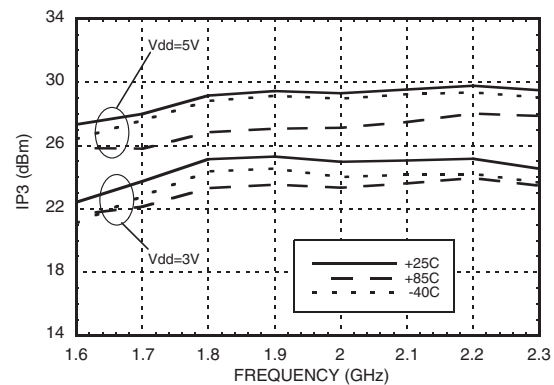
LNA - Return Loss vs. Temperature [1]



LNA - Noise Figure vs. Temperature [3]



LNA - Output IP3 vs. Temperature, Output Power @ 0 dBm



[1] Vdd = 5V [2] Vdd = 3V [3] Measurement reference plane shown on evaluation PCB drawing.

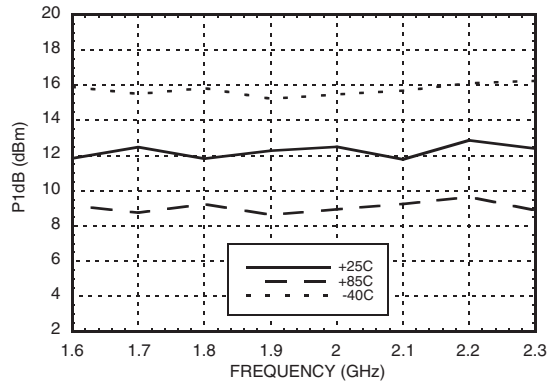
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

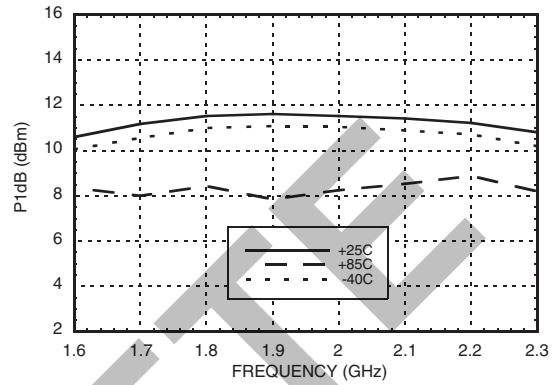


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

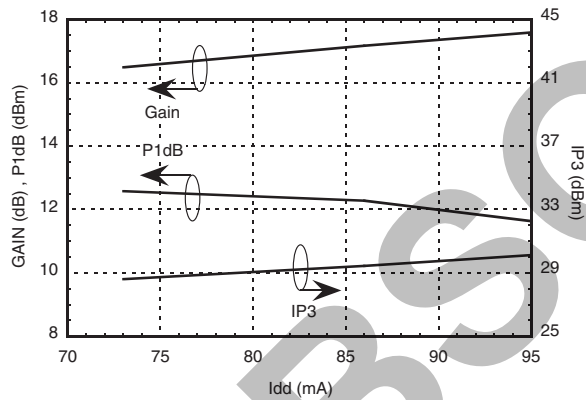
LNA - Output P1dB vs. Temperature [1]



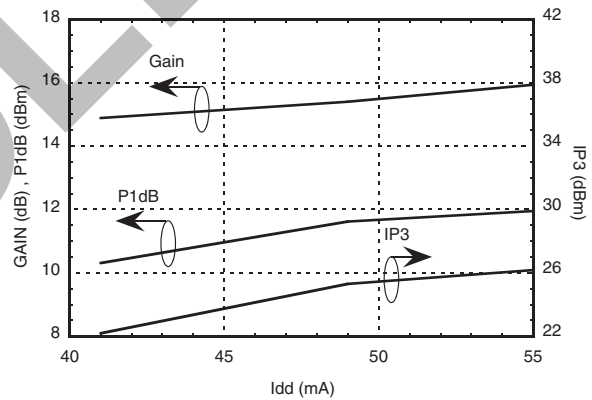
LNA - Output P1dB vs. Temperature [2]



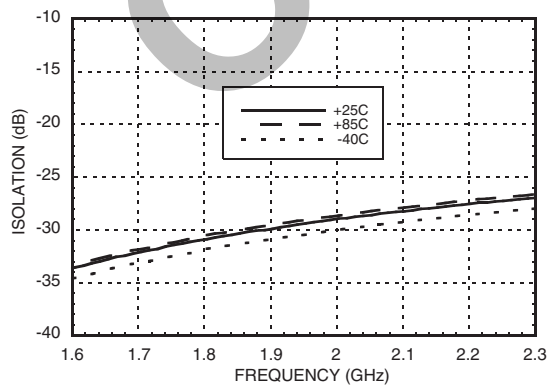
LNA - Gain, P1dB, Output IP3 vs. Current [1] @ 1900 MHz



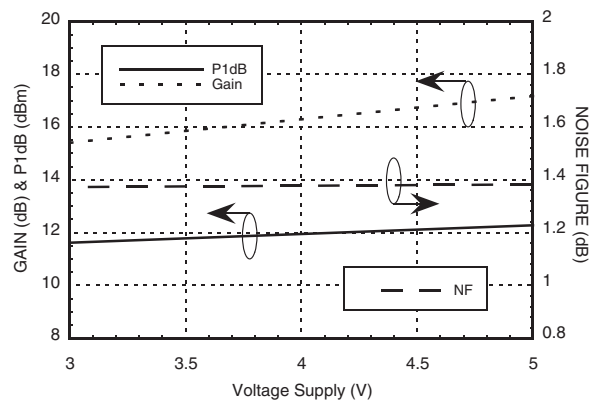
LNA - Gain, P1dB, Output IP3 vs. Current [2] @ 1900 MHz



LNA - Reverse Isolation vs. Temperature [1]



LNA - Output P1dB, Gain & Noise Figure [3] vs. Vdd @ 1900 MHz



[1] Vdd = 5V [2] Vdd = 3V [3] Measurement reference plane shown on evaluation PCB drawing.

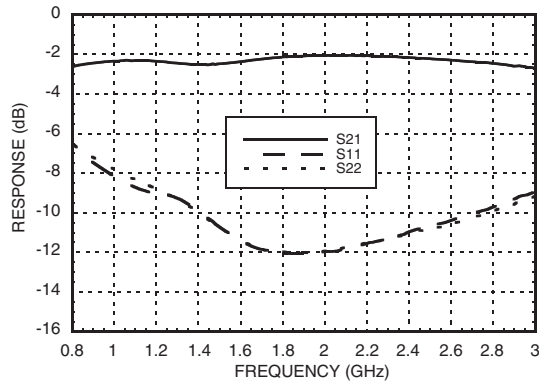
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

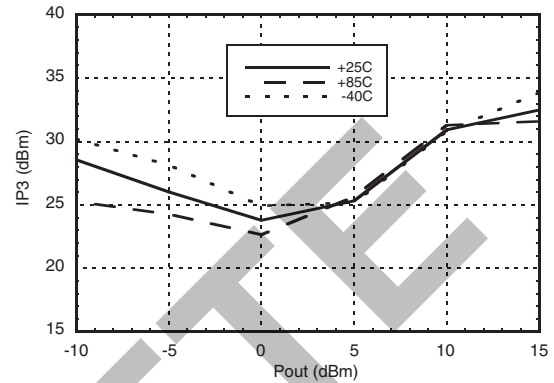


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

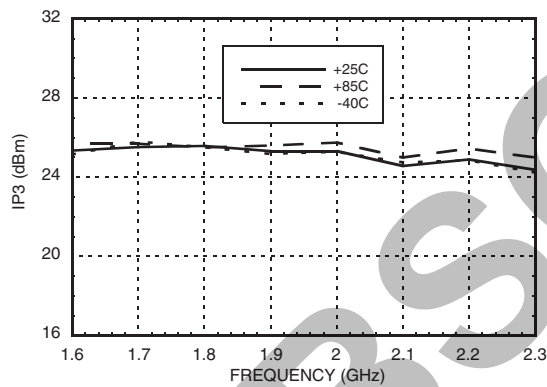
**Bypass Mode -
Broadband Gain & Return Loss**



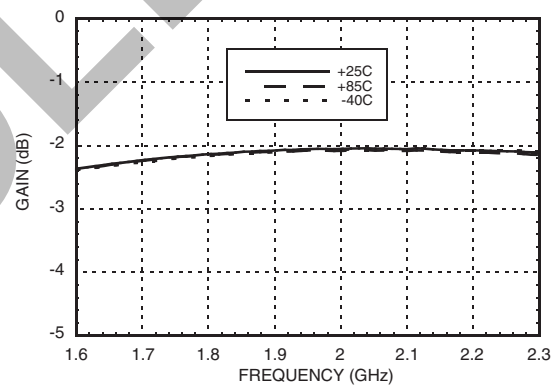
**Bypass Mode -
Input IP3 vs. Output Power @ 1900 MHz**



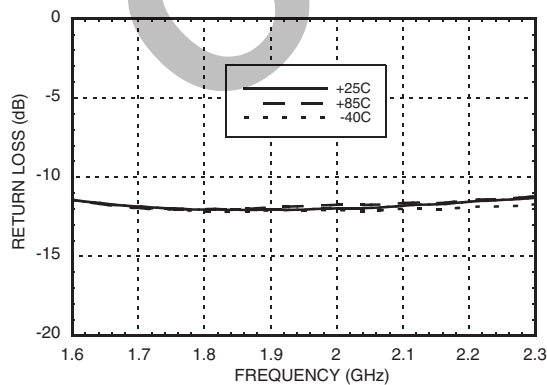
**Bypass Mode - Input IP3 vs.
Temperature, Output Power @ 5 dBm**



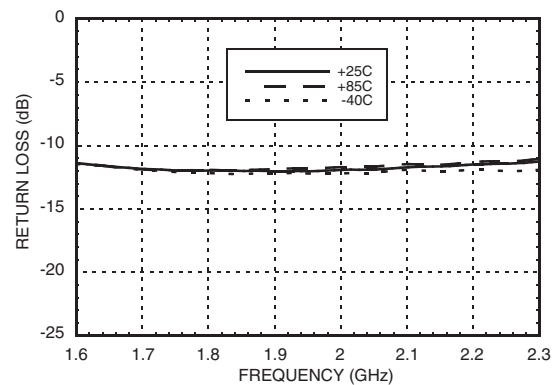
**Bypass Mode -
Insertion Loss vs. Temperature**



**Bypass Mode -
Input Return Loss vs. Temperature**



**Bypass Mode -
Output Return Loss vs. Temperature**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

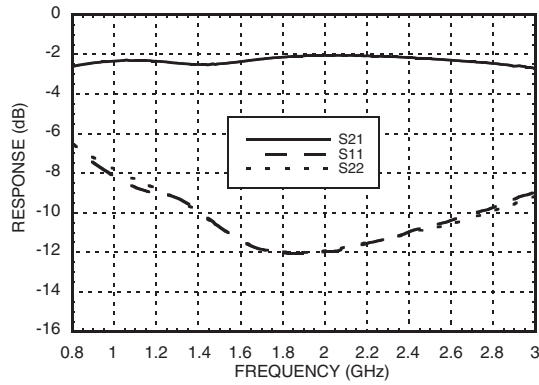


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

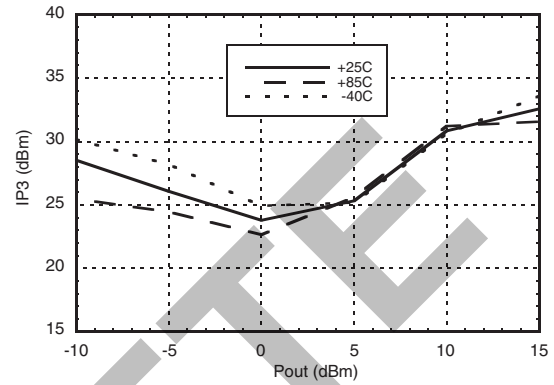
7

AMPLIFIERS - LOW NOISE - SMT

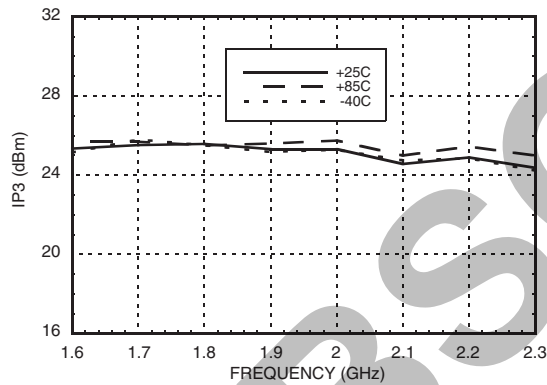
**Failsafe Mode -
Broadband Gain & Return Loss**



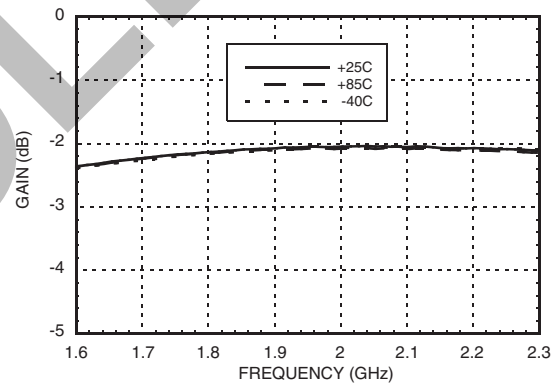
**Failsafe Mode -
Input IP3 vs. Output Power @ 1900 MHz**



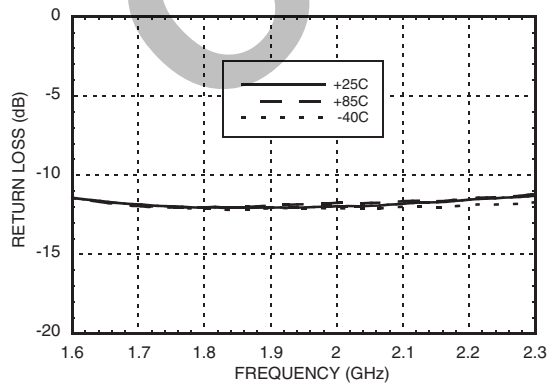
**Failsafe Mode - Input IP3 vs.
Temperature, Output Power @ 5 dBm**



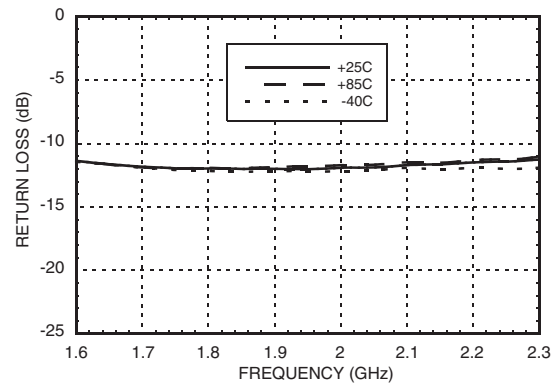
**Failsafe Mode -
Insertion Loss vs. Temperature**



**Failsafe Mode -
Input Return Loss vs. Temperature**



**Failsafe Mode -
Output Return Loss vs. Temperature**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**
Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+6 Vdc
Control Voltage (Vctl)	+6 Vdc
RF Input Power (RFIN)	LNA Mode +5 dBm Bypass / Fail safe Mode +20 dBm
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 10.71 mW/°C above 85 °C)	0.70 W
Thermal Resistance (channel to ground paddle)	93.33 °C/W
Storage Temperature	-65 to +150° C
Operating Temperature	-40 to +85° C
ESD Sensitivity (HBM)	Class 1A


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**
Typical Supply Current vs. Vdd

R _{bias} Ω	I _{dd} (mA)	
	V _{dd} = 3V	V _{dd} = 5V
0	55	95
15	49	86
47	41	73
180 [1]	28	50

[1] Recommended maximum R_{bias}
Truth Table

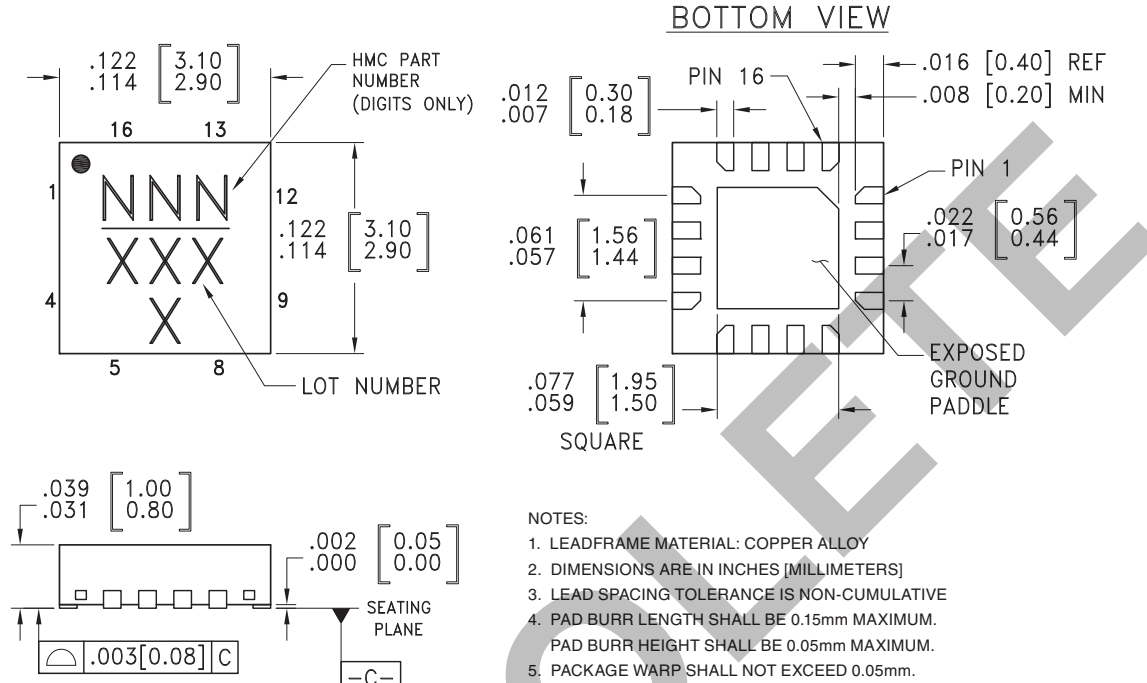
LNA Mode	V _{ctl} = V _{dd} = 3 to 5V
Bypass Mode	V _{ctl} = 0V, V _{dd} = 3 to 5V
Failsafe Mode	V _{ctl} = V _{dd} = N/C

OBSOLETE



**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

Outline Drawing

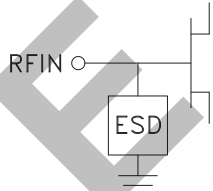


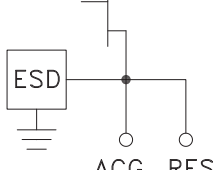
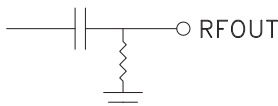

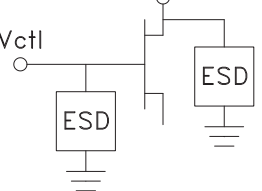


Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC669LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	669 XXXX
HMC669LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	669 XXXX

[1] Max peak reflow temperature of 235 °C
 [2] Max peak reflow temperature of 260 °C
 [3] 4-Digit lot number XXXX


**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**
7
Pin Descriptions

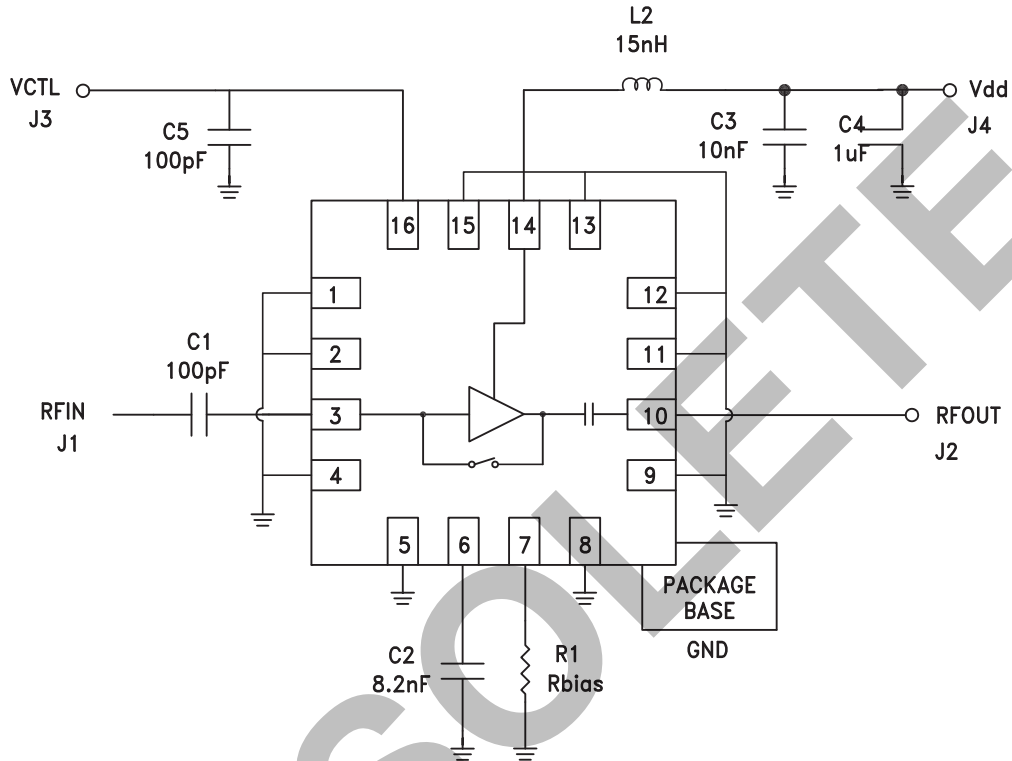
Pin Number	Function	Description	Interface Schematic
1, 2, 5, 8, 11, 12, 13, 15	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	RFIN	This pin is DC coupled. Off-chip DC blocking capacitor required.	
4, 9	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
6	ACG	AC Ground. Attach bypass capacitor per application circuit.	
7	RES	External resistor pin for current control. See table for external resistor value vs. bias current data.	
10	RFOUT	This pin is matched to 50 Ohms	
14	Vdd	Power Supply voltage pin. External bypass capacitors required.	
16	Vctl	Control voltage pin for LNA / Bypass Modes. Setting voltage equal to VDD enables LNA Mode. External Bypass capacitor required.	



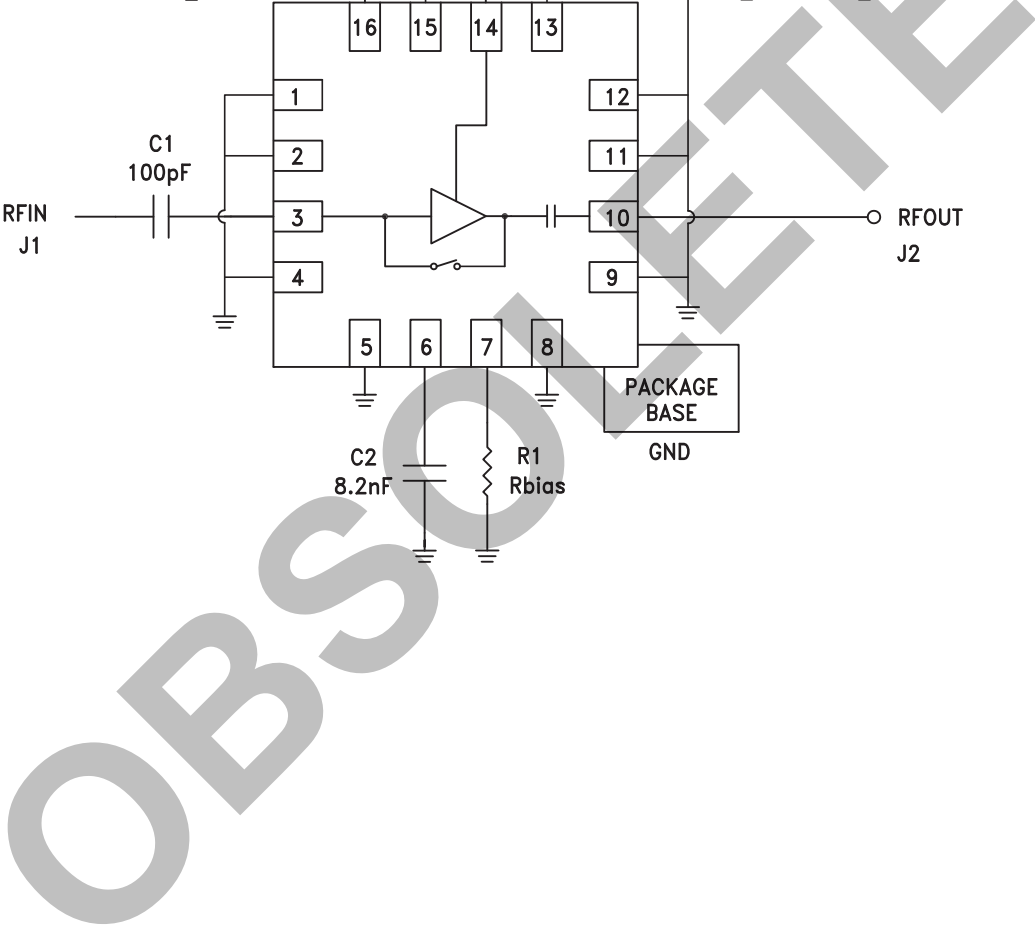
**GaAs PHEMT MMIC LNA w/
FAILSAFE BYPASS MODE, 1700 - 2200 MHz**

7

Application Circuit

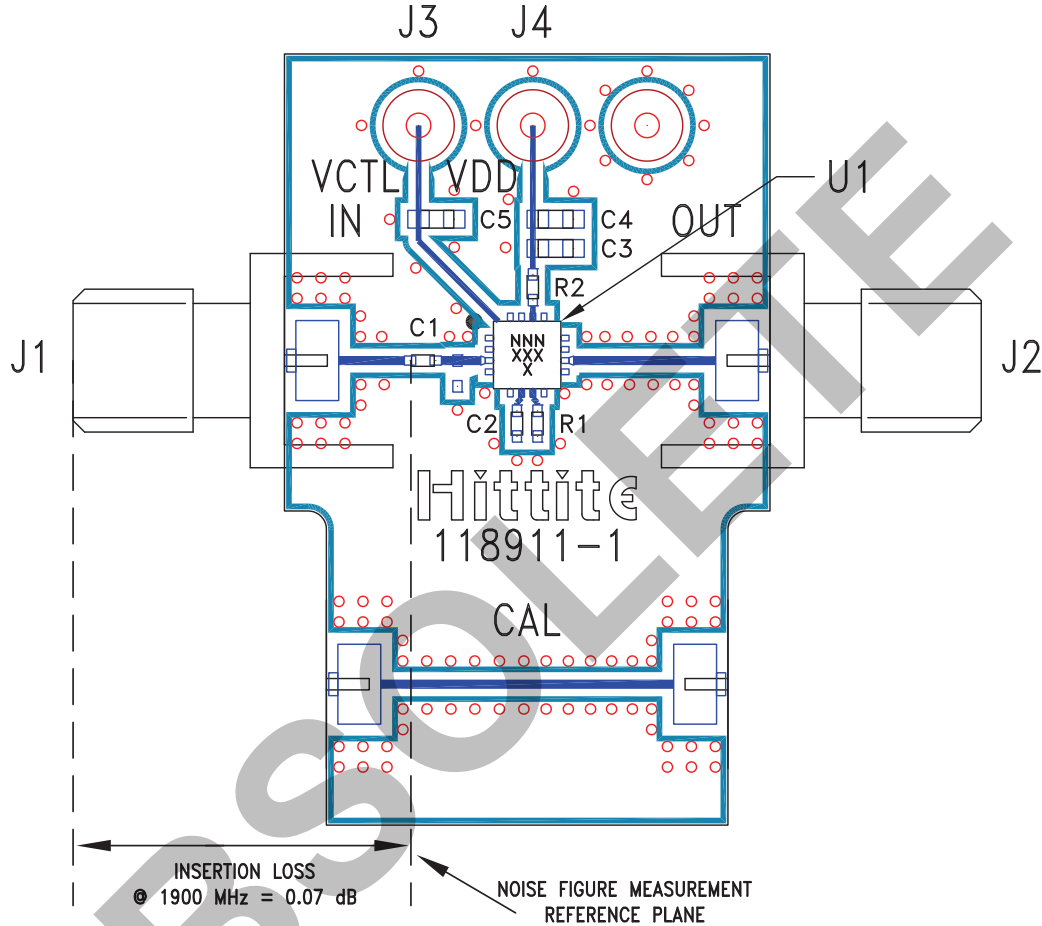


AMPLIFIERS - LOW NOISE - SMT





Evaluation PCB



List of Materials for Evaluation PCB 121923 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1	82 pF Capacitor, 0402 Pkg.
C2	8200 pF Capacitor, 0402 Pkg.
C3	10 nF Capacitor, 0603 Pkg.
C4	1 μF Capacitor, 0603 Pkg.
C5	100 pF Capacitor, 0603 Pkg.
R1	15 Ohm Resistor, 0402 Pkg.
R2	0 Ohm Resistor, 0402 Pkg.
U1	HMC669LP3(E) Amplifier
PCB [2]	118911 Evaluation Board

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [RF Amplifier](#) category:

Click to view products by [Analog Devices](#) manufacturer:

Other Similar products are found below :

[A82-1](#) [BGA622H6820XTSA1](#) [BGA 728L7 E6327](#) [BGB719N7ESDE6327XTMA1](#) [HMC397-SX](#) [HMC405](#) [HMC561-SX](#) [HMC8120-SX](#)
[HMC8121-SX](#) [HMC-ALH382-SX](#) [HMC-ALH476-SX](#) [SE2433T-R](#) [SMA3101-TL-E](#) [SMA39](#) [A66-1](#) [A66-3](#) [A67-1](#) [A81-2](#) [LX5535LQ](#)
[LX5540LL](#) [MAAM02350](#) [HMC3653LP3BETR](#) [HMC549MS8GETR](#) [HMC-ALH435-SX](#) [SMA101](#) [SMA32](#) [SMA411](#) [SMA531](#)
[SST12LP19E-QX6E](#) [WPM0510A](#) [HMC5929LS6TR](#) [HMC5879LS7TR](#) [HMC1087F10](#) [HMC1086](#) [HMC1016](#) [SMA1212](#) [MAX2689EWS+T](#)
[MAAMSS0041TR](#) [MAAM37000-A1G](#) [LTC6430AIUF-15#PBF](#) [SMA70-2](#) [SMA4011](#) [A231](#) [HMC-AUH232](#) [LX5511LQ](#) [LX5511LQ-TR](#)
[HMC7441-SX](#) [HMC-ALH310](#) [XD1001-BD-000V](#) [A4011](#)